



16-Bit, Dual, Parallel Input, Multiplying Digital-to-Analog Converter

FEATURES

- ±0.5LSB DNL
- ±1LSB INL
- Low Noise: 12nV/√Hz
- Low Power Operation: I_{DD} = 1μA per Channel at 2.7V
- 2mA Full-Scale Current, with V_{REF} = 10V
- Settling Time: 0.5µs
- 16-Bit Monotonic
- 4-Quadrant Multiplying Reference Inputs
- Reference Bandwidth: 10MHz
- Reference Input: ±18V
- Reference Dynamics: -105 THD
- Midscale or Zero Scale Reset
- Analog Power Supply: +2.7V to +5.5V
- TSSOP-38 Package
- Industry-Standard Pin Configuration
- Pin-Compatible with the 14-Bit DAC8805
- Temperature Range: –40°C to +125°C

APPLICATIONS

- Automatic Test Equipment
- Instrumentation
- Digitally Controlled Calibration
- Industrial Control PLCs

DESCRIPTION

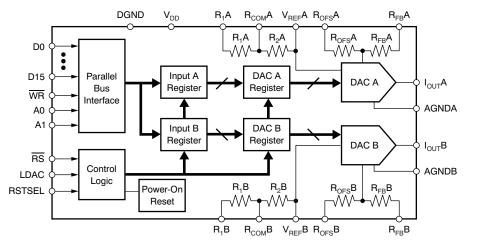
The DAC8822 dual, multiplying digital-to-analog converter (DAC) is designed to operate from a single 2.7V to 5.5V supply.

The applied external reference input voltage V_{REF} determines the full-scale output current. An internal feedback resistor (R_{FB}) provides temperature tracking for the full-scale output when combined with an external, current-to-voltage (I/V) precision amplifier.

A RSTSEL pin allows system reset assertion (\overline{RS}) to force all registers to zero code when RSTSEL = '0', or to midscale code when RSTSEL = '1'. Additionally, an internal power-on reset forces all registers to zero or midscale code at power-up, depending on the state of the RSTSEL pin.

A parallel interface offers high-speed communications. The DAC8822 is packaged in a space-saving TSSOP-38 package and has an industry-standard pinout. The device is specified from -40° C to $+125^{\circ}$ C.

For a 14-bit, pin-compatible version, see the DAC8805.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. All trademarks are the property of their respective owners.

DAC8822



SBAS390A-DECEMBER 2006-REVISED MARCH 2007



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION⁽¹⁾

PRODUCT	RELATIVE ACCURACY (LSB)	DIFFERENTIAL NONLINEARITY (LSB)	PACKAGE-LEAD (DESIGNATOR)	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING
DAC8822QB	±2	±1	TSSOP-38 (DBT)	–40°C to +125°C	DAC8822
DAC8822QC	±1	±1	TSSOP-38 (DBT)	–40°C to +125°C	DAC8822

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		DAC8822	UNIT
V _{DD} to GND		-0.3 to +7	V
Digital input vo	Itage to GND	-0.3 to +V _{DD} + 0.3	V
V (I _{OUT}) to GND		-0.3 to +V _{DD} + 0.3	V
REF, R _{OFS} , R _F	B, R ₁ , R _{COM} to AGND, DGND	±25	V
Operating tem	perature range	-40 to +125	°C
Storage tempe	rature range	-65 to +150	°C
Junction tempe	erature range (T _J max)	+150	°C
Power dissipat	ion	$(T_J max - T_A) / R_{\theta JA}$	W
Thermal imped	lance, R _{θJA}	53	°C/W
CCD rating	Human Body Model (HBM)	4000	V
ESD rating	Charged Device Model (CDM)	500	V

(1) Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

All specifications at $T_A = -40^{\circ}C$ to +125°C, $V_{DD} = +2.7V$ to +5.5V, $I_{OUT} = virtual GND$, GND = 0V, and $V_{REF} = 10V$, unless otherwise noted.

PARAMETER		CONDITIONS	MIN	DAC8822 TYP	MAX	UNITS
STATIC PERFORMANCE		· ·				
Resolution			16			Bits
		DAC8822QB			±2	LSB
Relative accuracy	INL	DAC8822QC			±1	LSB
Differential nonlinearity	DNL			±0.5	±1	LSB
Output leakage current		Data = 0000h, T _A = +25°C			10	nA
Output leakage current		Data = 0000h, Full temperature range			20	nA
-		Unipolar, data = FFFFh		±1	±4	mV
Full-scale gain error		Bipolar, data = FFFFh		±1	±4	mV
Full-scale temperature coefficient				±1	±2	ppm/°C
5		T _A = +25°C		±1	±3	mV
Bipolar zero error		Full temperature range		±1	±3	mV
Power-supply rejection ratio	PSRR	V _{DD} = 5V ±10%		±0.2	±1.0	LSB/V
OUTPUT CHARACTERISTICS ⁽¹⁾		,				
Output current				2		mA
Output capacitance		Code dependent		50		pF
REFERENCE INPUT						
Reference voltage range	V _{REF}		-18		18	V
Input resistance (unipolar)	R _{REF}		4	5	6	kΩ
Input capacitance				5		pF
R ₁ , R ₂			4	5	6	kΩ
Feedback and offset resistance	R _{OFS} , R _{FB}		8	10	12	kΩ
LOGIC INPUTS AND OUTPUT ⁽¹⁾						
	VIL	V _{DD} = +2.7V			0.6	V
Input low voltage	V _{IL}				0.8	V
	VIH		2.1			V
Input high voltage	V _{IH}		2.4			V
Input leakage current	I _{IL}			0.001	1	μA
Input capacitance	C _{IL}				8	pF
POWER REQUIREMENTS	-12					F.
Supply voltage	V _{DD}		2.7		5.5	V
	. 00	Normal operation, logic inputs = 0V		3	6	μA
Supply current	I _{DD}			3	6	μΑ
	-00	V_{DD} = +2.7V to +3.6V, V_{IH} = V_{DD} and V_{IL} = GND		1	3	μΑ
AC CHARACTERISTICS ⁽¹⁾⁽²⁾						r.
		To 0.0015% of full-scale,		0.7		
Output current settling time	ts	data = 0000h to FFFFh to 0000h		0.5		μs
Reference multiplying BW	BW – 3dB	V_{REF} = 5 V_{PP} , data = FFFFh, 2-quadrant mode		10		MHz
DAC glitch impulse		V _{REF} = 0V to 10V, data = 7FFFh to 8000h to 7FFFh		5		nV–s
Feedthrough error	V_{OUT}/V_{REF}	Data = 0000h, V_{REF} = 100kHz, ±10V _{PP} , 2-quadrant mode		-70		dB
Crosstalk error	$V_{OUT}A/V_{REF}B$	Data = 0000h, $V_{REF}B$ = 100m V_{RMS} , f = 100kHz		-100		dB
Digital feedthrough		LDAC = logic low, $V_{REF} = -10V$ to + 10V Any code change		1		nV–s
Total harmonic distortion	THD	$V_{REF} = 6V_{RMS}$, data = FFFFh, f = 1kHz		-105		dB
Output noise density	e _N	f = 1kHz, BW = 1Hz, 2-quadrant mode		12		nV/√Hz

Specified by design and characterization; not production tested.
All ac characteristic tests are performed in a closed-loop system using a THS4011 I-to-V converter amplifier.

DBT PACKAGE TSSOP-38 (TOP VIEW) 0 38 D1 1 D2 D0 2 37 D3 3 36 D4 $\mathsf{R}_{\mathsf{OFS}}\mathsf{A}$ $\mathsf{R}_{\mathsf{FB}}\mathsf{A}$ 4 35 D5 R_1A 5 34 D6 $\mathsf{R}_{\mathsf{COM}}\mathsf{A}$ 6 33 D7 $\mathsf{V}_{\mathsf{REF}}\mathsf{A}$ 7 32 D8 8 31 D9 $I_{\rm OUT}A$ AGNDA 9 30 D10 DAC8822 DGND 10 29 VDD AGNDB 11 28 D11 I_{OUT}B 12 27 D12 $V_{\text{REF}}B$ 13 26 D13 $\mathbf{R}_{\mathrm{COM}}\mathbf{B}$ 14 25 D14 R₁B 15 24 D15 RS $\mathbf{R}_{\mathrm{FB}}\mathbf{B}$ 16 23 $\mathbf{R}_{\mathrm{OFS}}\mathbf{B}$ 17 22 RSTSEL WR 18 21 LDAC A0 19 20 A1

PIN ASSIGNMENTS

PIN ASSIGNMENTS (continued)

Table 1. TERMINAL FUNCTIONS

PIN #	NAME	DESCRIPTION
1, 2, 24-28, 30-38	D0-D15	Digital Input Data Bits D0 to D15. Signal level must be $\leq V_{DD}$ +0.3V. D15 is MSB.
3	R _{OFS} A	Bipolar Offset Resistor A. Accepts up to $\pm 18V$. In 2-quadrant mode, R _{OFS} A ties to R _{FB} A. In 4-quadrant mode, R _{OFS} A ties to R ₁ A and the external reference.
4	R _{FB} A	Internal Matching Feedback Resistor A. Connects to the external op amp for I-V conversion.
5	R ₁ A	4-Quadrant Resistor. In 2-quadrant mode, R ₁ A shorts to the V _{REF} A pin. In 4-quadrant mode, R ₁ A ties to R _{OFS} A and the reference input.
6	R _{COM} A	Center Tap Point of the Two 4-Quadrant Resistors, R_1A and R_2A . In 2-quadrant mode, $R_{COM}A$ shorts to the V_{REF} pin. In 4-quadrant mode, $R_{COM}A$ ties to the inverting node of the reference amplifier.
7	V _{REF} A	DAC A Reference Input in 2-Quadrant Mode, R_2 Terminal in 4-Quadrant Mode. In 2-quadrant mode, $V_{REF}A$ is the reference input with constant input resistance versus code. In 4-quadrant mode, $V_{REF}A$ is driven by the external reference amplifier.
8	I _{OUT} A	DAC A Current Output. Connects to the inverting terminal of external precision I-V op amp for voltage output.
9	AGNDA	DAC A Analog Ground.
10	DGND	Digital Ground.
11	AGNDB	DAC B Analog Ground.
12	I _{OUT} B	DAC B Current Output. Connects to the inverting terminal of external precision I-V op amp for voltage output.
13	V _{REF} B	DAC B Reference Input in 2-Quadrant Mode, R_2 Terminal in 4-Quadrant Mode. In 2-quadrant mode, $V_{REF}B$ is the reference input with constant input resistance versus code. In 4-quadrant mode, $V_{REF}B$ is driven by the external reference amplifier.
14	R _{COM} B	Center Tap Point of the Two 4-Quadrant Resistors, R_1B and R_2B . In 2-quadrant mode, $R_{COM}B$ shorts to the V_{REF} pin. In 4-quadrant mode, $R_{COM}B$ ties to the inverting node of the reference amplifier.
15	R₁B	4-Quadrant Resistor. In 2-quadrant mode, R ₁ B shorts to the V _{REF} B pin. In 4-quadrant mode, R ₁ B ties to R _{OFS} B and the reference input.
16	R _{FB} B	Internal Matching Feedback Resistor B. Connects to external op amp for I-V conversion.
17	R _{OFS} B	Bipolar Offset Resistor B. Accepts up to $\pm 18V$. In 2-quadrant mode, R _{OFS} B ties to R _{FB} B. In 4-quadrant mode, R _{OFS} B ties to R ₁ B and the external reference.
18	WR	Write Control Digital Input In, Active Low. \overline{WR} enables input registers. Signal level must be $\leq V_{DD} + 0.3V$.
19	A0	Address 0. Signal level must be $\leq V_{DD} + 0.3V$.
20	A1	Address 1. Signal level must be $\leq V_{DD} + 0.3V$.
21	LDAC	Digital Input Load DAC Control. Signal level must be $\leq V_{DD}$ + 0.3V. See the Function of Control Inputs table for details.
22	RSTSEL	Power-On Reset State. RSTSEL = 0 corresponds to zero-scale reset. RSTSEL = 1 corresponds to midscale reset. The signal level must be $\leq V_{DD} + 0.3V$.
23	RS	Reset. Active low resets both input and DAC registers. Resets to zero-scale if RSTSEL= 0, and to midscale if RSTSEL = 1. Signal level must be equal to or less than VDD + 0.3 V.
29	V _{DD}	Positive Power Supply Input. The specified range of operation is 2.7V to 5.5V.

TIMING AND FUNCTIONAL INFORMATION

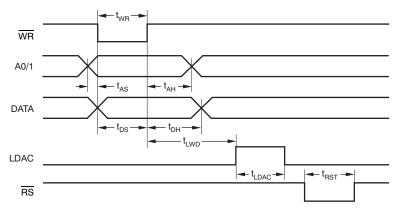


Figure 1. Timing Diagram

TIMING CHARACTERISTICS

All specifications at $T_A = -40^{\circ}C$ to +125°C, I_{OUT} = virtual GND, GND = 0V, and V_{REF} = 10V, unless otherwise noted

				DAC8822			
PARAMETER		CONDITIONS	MIN	TYP MAX		UNITS	
Data ta MD actus tima		$V_{DD} = +5.0V$	10			ns	
Data to WR setup time	t _{DS}	$V_{DD} = +2.7V$	10			ns	
A0/1 to $\overline{\rm WR}$ setup time		$V_{DD} = +5.0V$	10			ns	
AU/T to WK setup time	t _{AS}	$V_{DD} = +2.7V$	10			ns	
Data to \overline{WR} hold time		$V_{DD} = +5.0V$	0			ns	
Data to we hold time	t _{DH}	$V_{DD} = +2.7V$	0			ns	
		$V_{DD} = +5.0V$	0			ns	
A0/1 to WR hold time	t _{AH}	$V_{DD} = +2.7V$	0			ns	
WR pulse width		$V_{DD} = +5.0V$	10			ns	
wik pulse width	t _{WR}	$V_{DD} = +2.7V$	10			ns	
		$V_{DD} = +5.0V$	10			ns	
LDAC pulse width	t _{LDAC}	$V_{DD} = +2.7V$	10			ns	
		$V_{DD} = +5.0V$	10			ns	
RS pulse width	t _{RST}	$V_{DD} = +2.7V$	10			ns	
		V _{DD} = +5.0V	0			ns	
WR to LDAC delay time	t _{LWD}	$V_{DD} = +2.7V$	0			ns	

Table 2. Address Decoder Pins

A1	A0	OUTPUT UPDATE
0	0	DAC A
0	1	None
1	0	DAC A and DAC B
1	1	DAC B

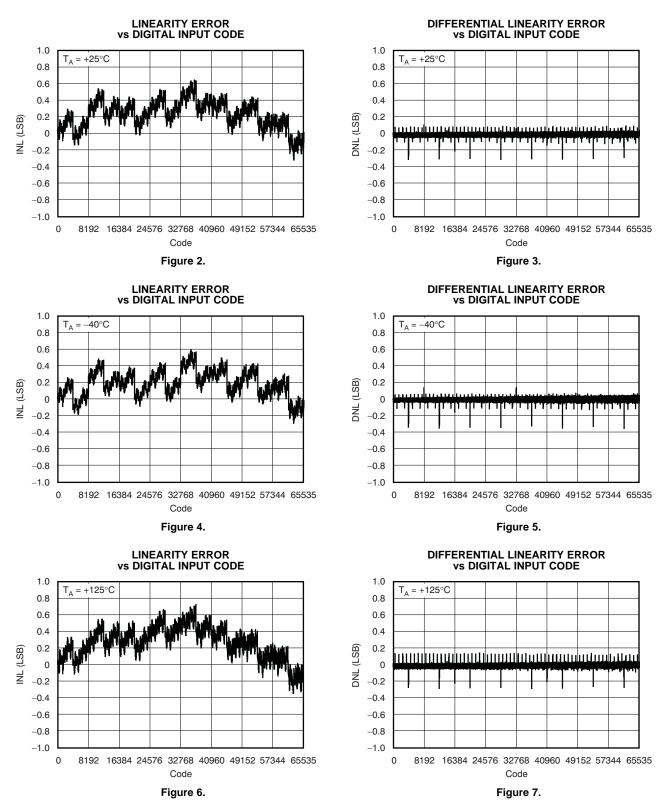
Table 3. Function of Control Inputs

CO	ONTROL INPU	ITS	
RS	WR	LDAC	REGISTER OPERATION
0	х	х	Asynchronous operation. Reset the input and DAC register to '0' when the RSTSEL pin is tied to DGND, and to midscale when RSTSEL is tied to V_{DD} .
1	0	0	Load the input register with all 16 data bits.
1	1	1	Load the DAC register with the contents of the input register.
1	0	1	The input and DAC register are transparent.
1	U	U	LDAC and \overline{WR} are tied together and programmed as a pulse. The 16 data bits are loaded into the input register on the falling edge of the pulse and then loaded into the DAC register on the rising edge of the pulse.
1	1	0	No register operation.



TYPICAL CHARACTERISTICS: V_{DD} = +5V

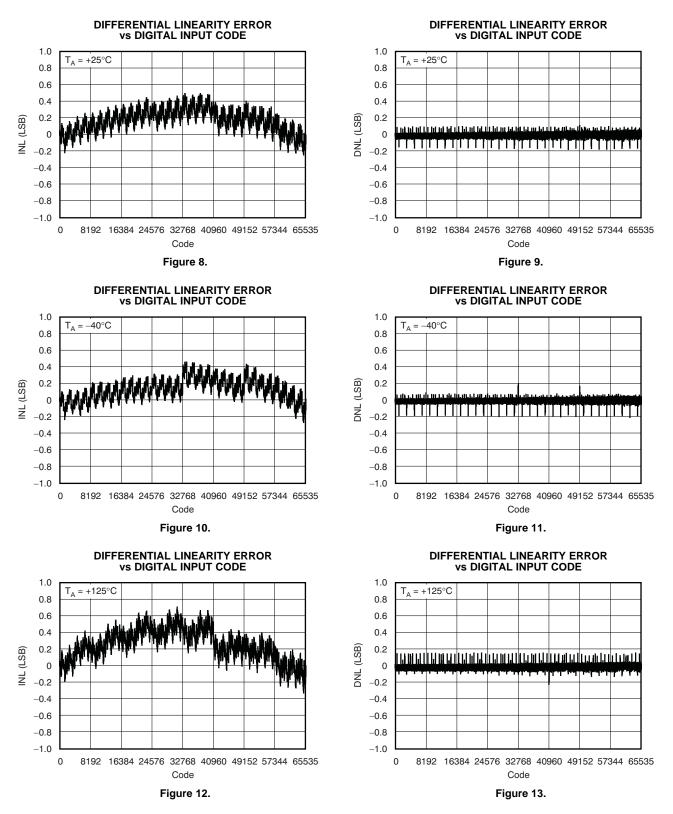
Channel A



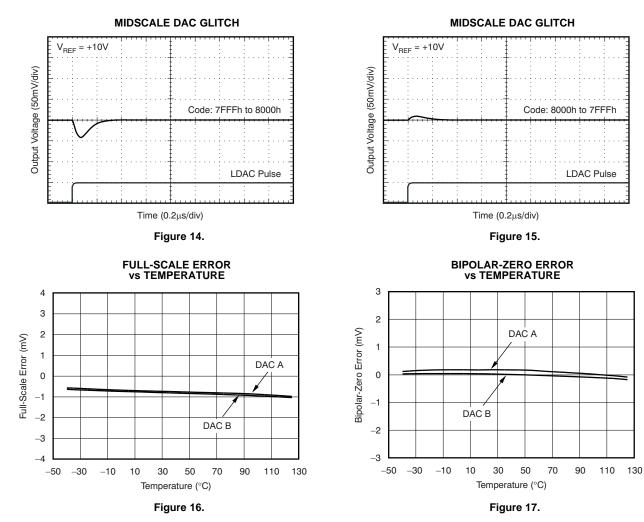


TYPICAL CHARACTERISTICS: V_{DD} = +5V (continued)

Channel B



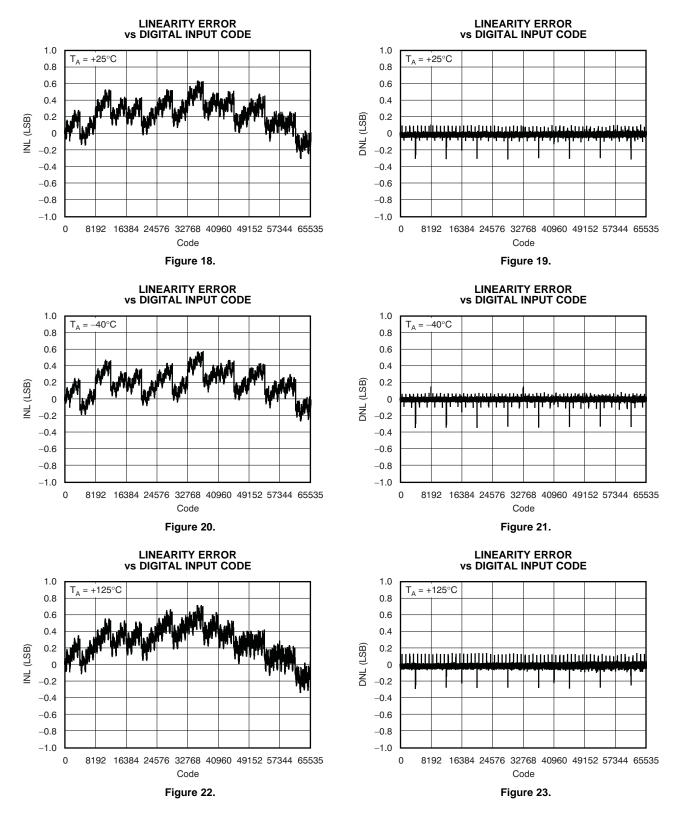
TYPICAL CHARACTERISTICS: $V_{DD} = +5V$ (continued)





TYPICAL CHARACTERISTICS: V_{DD} = +2.7V

Channel A



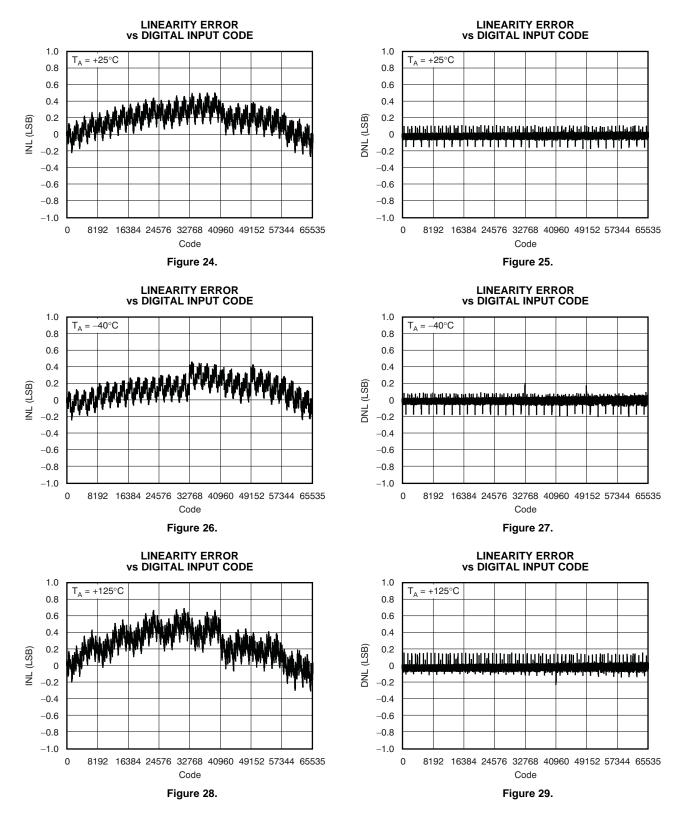
DAC8822

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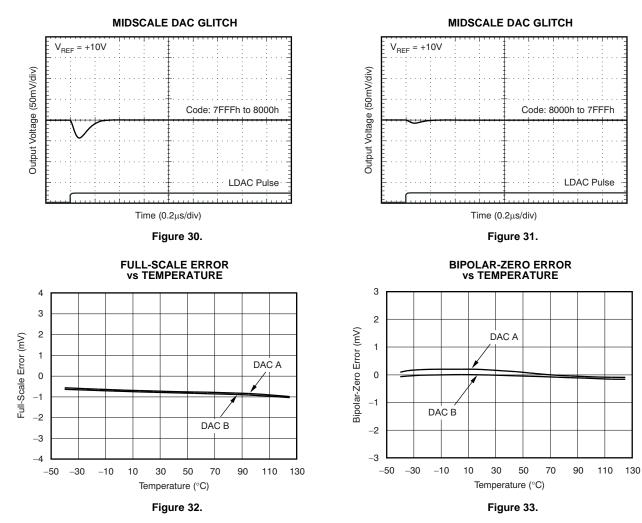


TYPICAL CHARACTERISTICS: V_{DD} = +2.7V (continued)

Channel B



TYPICAL CHARACTERISTICS: $V_{DD} = +2.7V$ (continued)





TYPICAL CHARACTERISTICS: V_{DD} = +2.7V and +5V

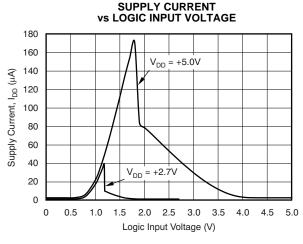


Figure 34.

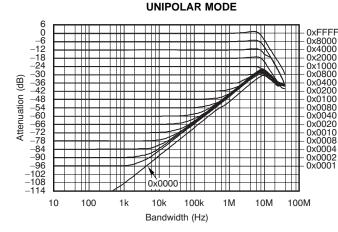
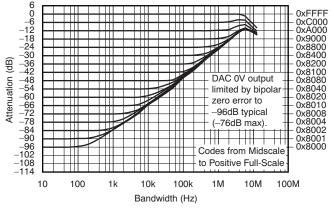


Figure 35.

REFERENCE MULTIPLYING BANDWIDTH

REFERENCE MULTIPLYING BANDWIDTH BIPOLAR MODE





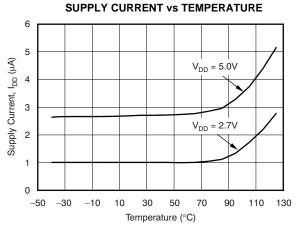
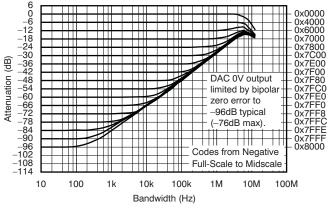


Figure 38.

REFERENCE MULTIPLYING BANDWIDTH BIPOLAR MODE





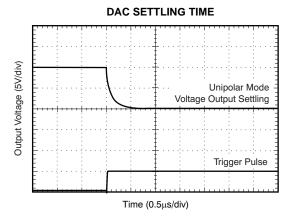


Figure 39.

THEORY OF OPERATION

The DAC8822 is a multiplying, dual-channel, current output, 16-bit DAC. The architecture, illustrated in Figure 40, is an R-2R ladder configuration with the three MSBs segmented. Each 2R leg of the ladder is either switched to GND or to the I_{OUT} terminal. The I_{OUT} terminal of the DAC is held at a virtual GND potential by the use of an external I/V converter op amp. The R-2R ladder is connected to an external reference input (V_{REF}) that determines the DAC full-scale output current. The R-2R ladder presents a code-independent load impedance to the external reference of $5k\Omega \pm 25\%$. The external reference voltage can vary in a range of -18V to +18V, thus providing bipolar I_{OUT} current operation. By using an external I/V converter op amp and the R_{FB} resistor in the DAC8822, an output voltage range of $-V_{REF}$ to $+V_{REF}$ can be generated.

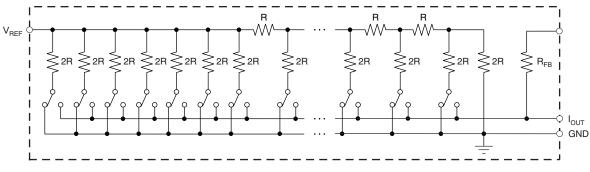


Figure 40. Equivalent R-2R DAC Circuit

The DAC output voltage is determined by V_{REF} and the digital data (D) according to Equation 1:

$$V_{\text{OUT}} A/B = -V_{\text{REF}} \times \frac{D}{65536}$$
(1)

Each DAC code determines the 2R-leg switch position to either GND or I_{OUT} . The external I/V converter op amp noise gain will also change because the DAC output impedance (as seen looking into the I_{OUT} terminal) changes versus code. Because of this change in noise gain, the external I/V converter op amp must have a sufficiently low offset voltage such that the amplifier offset is not modulated by the DAC I_{OUT} terminal impedance change. External op amps with large offset voltages can produce INL errors in the transfer function of the DAC8822 because of offset modulation versus DAC code. For best linearity performance of the DAC8822, an op amp (such as the OPA277) is recommended, as shown in Figure 41. This circuit allows V_{REF} to swing from -10V to +10V.

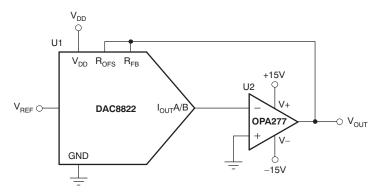


Figure 41. Voltage Output Configuration



APPLICATION INFORMATION

DIGITAL INTERFACE

The parallel bus interface of the DAC8822 is comprised of a 16-bit data bus D0—D15, address lines A0 and A1, and a WR control signal. Timing and control functionality are shown in Figure 1, and described in Table 2 and Table 3. The address lines must be set up and stable before the WR signal goes low, to prevent loading improper data to an undesired input register.

Both channels of the DAC8822 can be simultaneously updated by control of the LDAC signal, as shown in Figure 1. Reset control (\overline{RS}) and reset select control (RSTSEL) signals are provided to allow user reset ability to either zero scale or midscale codes of both the input and DAC registers.

STABILITY CIRCUIT

For a current-to-voltage (I/V) design, as shown in Figure 42, the DAC8822 current output (I_{OUT}) and the connection with the inverting node of the op amp should be as short as possible and laid out according to correct printed circuit board (PCB) layout design. For each code change, there is an output step function. If the gain bandwidth product (GBP) of the op amp is limited and parasitic capacitance is excessive at the inverting node, then gain peaking is possible. Therefore, a compensation capacitor C₁ (4pF to 20pF, typ) can be added to the design for circuit stability, as shown in Figure 42.

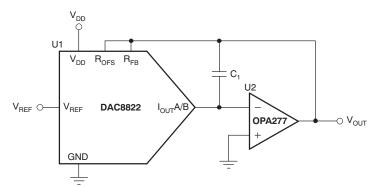


Figure 42. Gain Peaking Prevention Circuit with Compensation Capacitor

APPLICATION INFORMATION (continued)

BIPOLAR OUTPUT CIRCUIT

The DAC8822, as a 4-quadrant multiplying DAC, can be used to generate a bipolar output. The polarity of the full-scale output (I_{OUT}) is the inverse of the input reference voltage at V_{REF} .

Using a dual op amp, such as the OPA2277, full 4-quadrant operation can be achieved with minimal components. Figure 43 demonstrates a $\pm 10V_{OUT}$ circuit with a fixed +10V reference. The output voltage is shown in Equation 2:

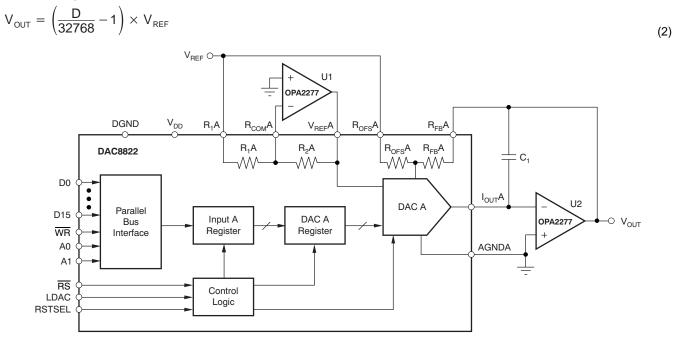


Figure 43. Bipolar Output Circuit for Channel A



(3)

APPLICATION INFORMATION (continued)

PROGRAMMABLE CURRENT SOURCE CIRCUIT

The DAC8822 can be integrated into the circuit in Figure 44 to implement an improved Howland current pump for precise V/I conversions. Bidirectional current flow and high-voltage compliance are two features of the circuit. With a matched resistor network, the load current of the circuit is shown by Equation 3:

$$I_{L}A/B = \frac{(R_{2}+R_{3})/R_{1}}{R_{3}} \times V_{REF} \times \frac{D}{65536}$$

The value of R_3 in the previous equation can be reduced to increase the output current drive of U3. U3 can drive ± 20 mA in both directions with voltage compliance limited up to 15V by the U3 voltage supply. Elimination of the circuit compensation capacitor (C₁) in the circuit is not suggested as a result of the change in the output impedance (Z₀), according to Equation 4:

$$Z_{\rm O} = \frac{R_{\rm 1}'R_{\rm 3}(R_{\rm 1}+R_{\rm 2})}{R_{\rm 1}(R_{\rm 2}'+R_{\rm 3}') - R_{\rm 1}'(R_{\rm 2}+R_{\rm 3})}$$
(4)

As shown in Equation 4, Z_0 with matched resistors is infinite and the circuit is optimum for use as a current source. However, if unmatched resistors are used, Z_0 is positive or negative with negative output impedance being a potential cause of oscillation. Therefore, by incorporating C_1 into the circuit, possible oscillation problems are eliminated. The value of C_1 can be determined for critical applications; for most applications, however, a value of several pF is suggested.

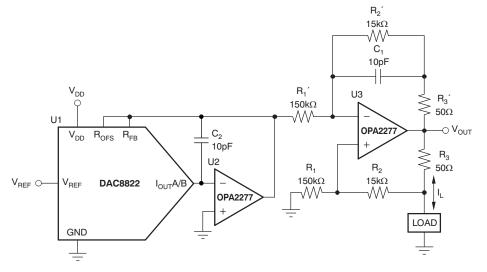


Figure 44. Programmable Bidirectional Current Source Circuit

CROSS-REFERENCE

The DAC8822 has an industry-standard pinout. Table 4 provides the cross-reference information.

PRODUCT	BIT	INL (LSB)	DNL (LSB)	SPECIFIED TEMPERATURE RANGE	PACKAGE DESCRIPTION	PACKAGE OPTION	CROSS- REFERENCE PART
DAC8822QB	16	2	1	–40°C to +125°C	TSSOP-38	DBT	AD5547B
DAC8822QC	16	1	1	-40°C to +125°C	TSSOP-38	DBT	N/A

Table 4. Cross-Reference



www.ti.com

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
DAC8822QBDBT	ACTIVE	TSSOP	DBT	38	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
DAC8822QBDBTG4	ACTIVE	TSSOP	DBT	38	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
DAC8822QBDBTR	ACTIVE	TSSOP	DBT	38	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
DAC8822QBDBTRG4	ACTIVE	TSSOP	DBT	38	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
DAC8822QCDBT	ACTIVE	TSSOP	DBT	38	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
DAC8822QCDBTG4	ACTIVE	TSSOP	DBT	38	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
DAC8822QCDBTR	ACTIVE	TSSOP	DBT	38	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
DAC8822QCDBTRG4	ACTIVE	TSSOP	DBT	38	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



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21-May-2010

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

TEXAS INSTRUMENTS





TAPE AND REEL INFORMATION

TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

*A	Il dimensions are nominal												
	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	DAC8822QBDBTR	TSSOP	DBT	38	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
	DAC8822QCDBTR	TSSOP	DBT	38	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

14-Jul-2012

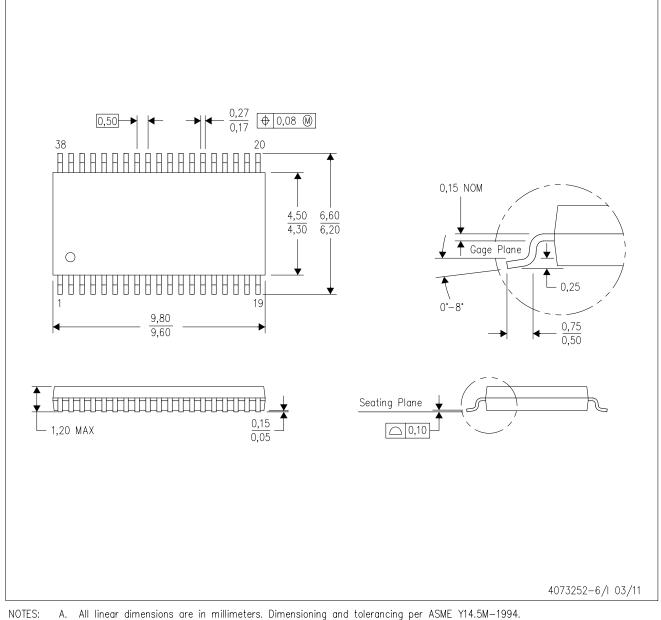


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DAC8822QBDBTR	TSSOP	DBT	38	2000	367.0	367.0	38.0
DAC8822QCDBTR	TSSOP	DBT	38	2000	367.0	367.0	38.0

DBT (R-PDSO-G38)

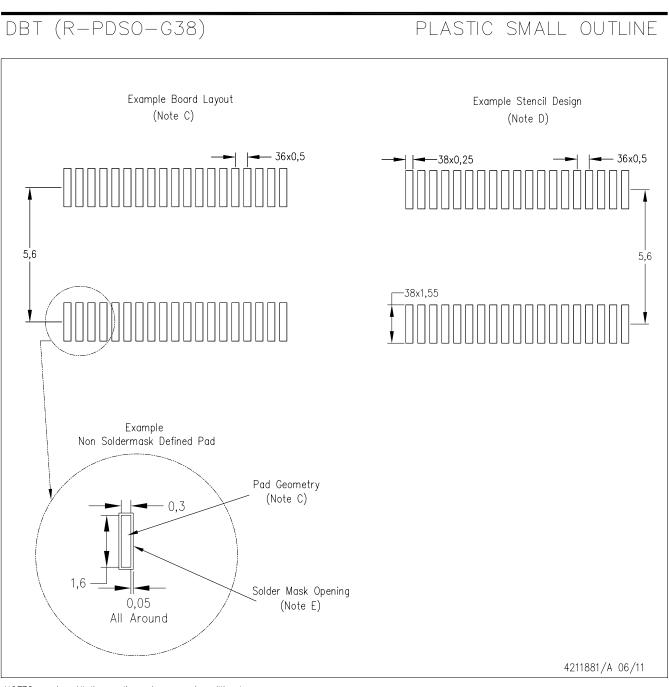
PLASTIC SMALL OUTLINE



B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-153.





- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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